

# Isolated High Current IGBT Gate Driver

## NCV57000

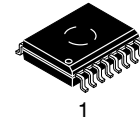
NCV57000 is a high-current single channel IGBT driver with internal galvanic isolation, designed for high system efficiency and reliability in high power applications. Its features include complementary inputs, open drain FAULT and Ready outputs, active Miller clamp, accurate UVLOs, DESAT protection, soft turn-off at DESAT, and separate high and low (OUTH and OUTL) driver outputs for system design convenience. NCV57000 accommodates both 5 V and 3.3 V signals on the input side and wide bias voltage range on the driver side including negative voltage capability. NCV57000 provides > 5 kVrms (UL1577 rating) galvanic isolation and > 1200 V<sub>IORM</sub> (working voltage) capabilities. NCV57000 is available in the wide-body SOIC-16 package with guaranteed 8 mm creepage distance between input and output to fulfill reinforced safety insulation requirements.

### Features

- High Current Output (+4/-6 A) at IGBT Miller Plateau Voltages
- Low Output Impedance for Enhanced IGBT Driving
- Short Propagation Delays with Accurate Matching
- Active Miller Clamp to Prevent Spurious Gate Turn-on
- DESAT Protection with Programmable Delay
- Negative Voltage (Down to -9 V) Capability for DESAT
- Soft Turn Off During IGBT Short Circuit
- IGBT Gate Clamping During Short Circuit
- IGBT Gate Active Pull Down
- Tight UVLO Thresholds for Bias Flexibility
- Wide Bias Voltage Range including Negative VEE2
- 3.3 V to 5 V Input Supply Voltage
- Designed for AEC-Q100 Certification
- 5000 V Galvanic Isolation (to meet UL1577 Requirements)
- 1200 V Working Voltage (per VDE0884-11 Requirements)
- High Transient Immunity
- High Electromagnetic Immunity
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

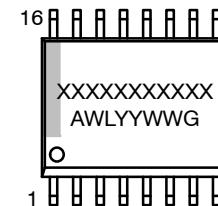
### Typical Applications

- Automotive Power Supplies
- HEV/EV Powertrain
- OBC
- BSG
- EV Charger
- PTC Heater



SOIC-16 WB  
CASE 751G-03

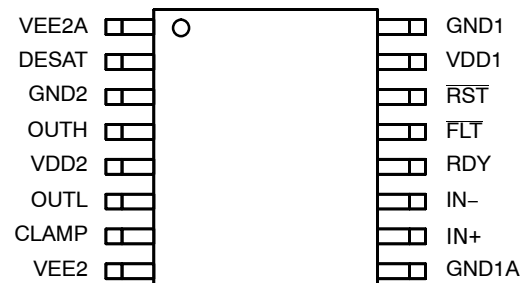
### MARKING DIAGRAM



XXXXX = Specific Device Code  
 A = Assembly Location  
 WL = Wafer Lot  
 YY = Year  
 WW = Work Week  
 G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

### PIN ASSIGNMENT



### ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

# NCV57000

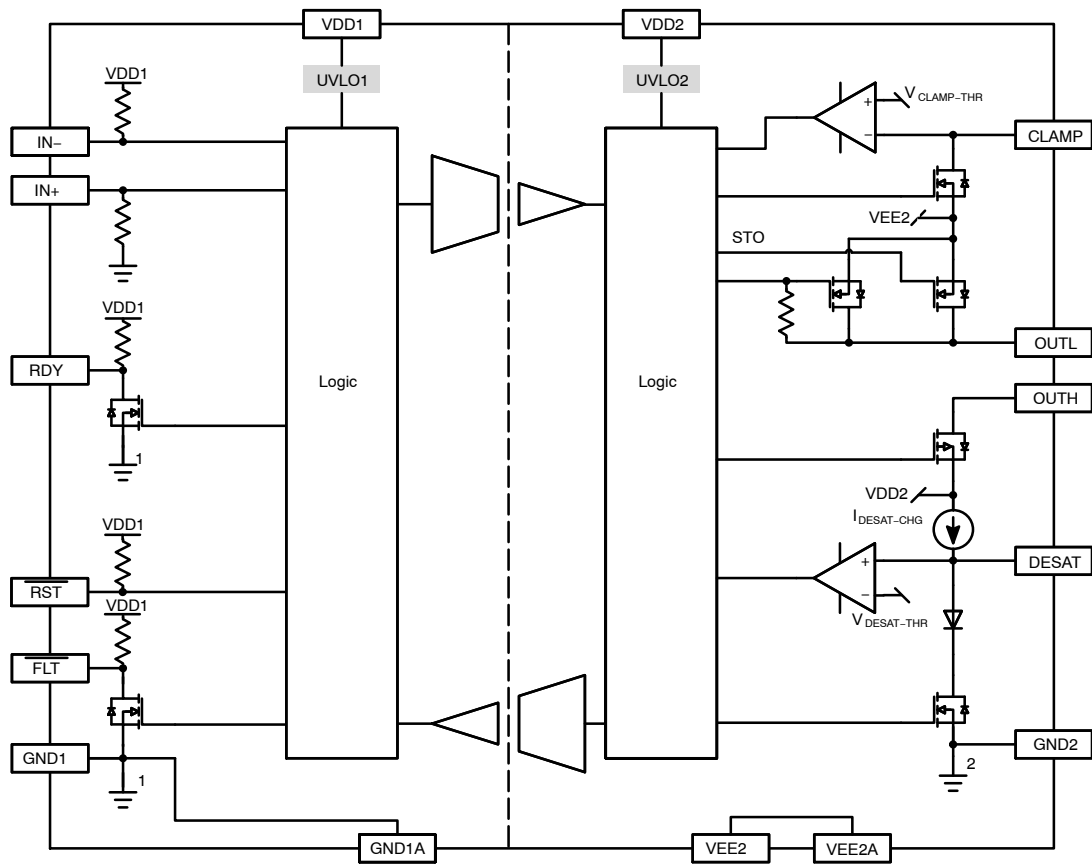


Figure 1. Simplified Block Diagram

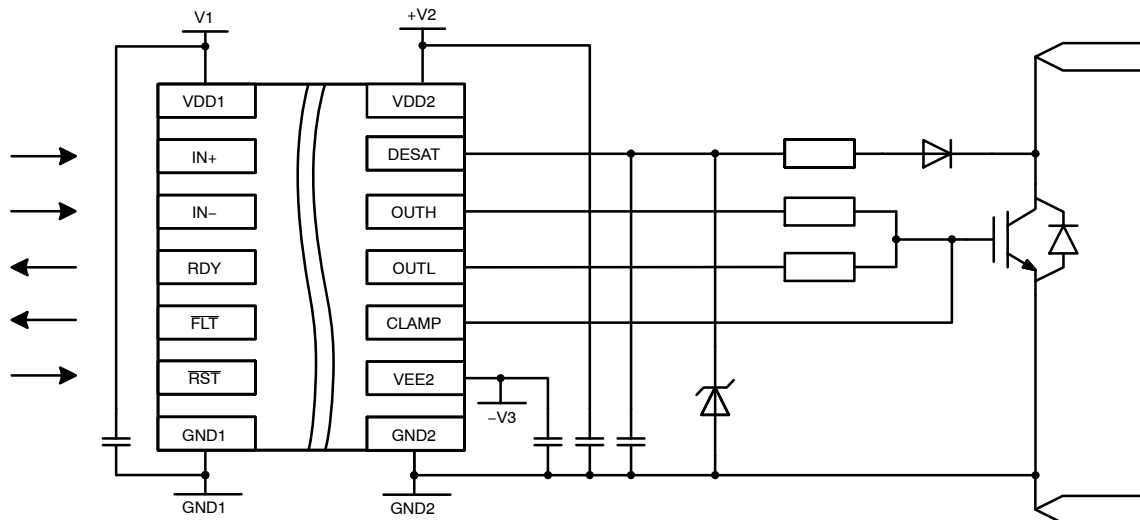


Figure 2. Simplified Application Schematics

**PIN DESCRIPTION**

| Pin Name          | No. | I/O   | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|-------------------|-----|-------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| V <sub>EE2A</sub> | 1   | Power | Output side negative power supply. A good quality bypassing capacitor is required from these pins to GND2 and should be placed close to the pins for best results. Connect it to GND2 for unipolar supply application.                                                                                                                                                                                                                                                                                                                                               |
| V <sub>EE2</sub>  | 8   |       |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| DESAT             | 2   | I/O   | Input for detecting the desaturation of IGBT due to a short circuit condition. An internal constant current source I <sub>DESAT-CHG</sub> charging an external capacitor connected to this pin allows a programmable blanking delay every ON cycle before DESAT fault is processed, thus preventing false triggering. When the DESAT voltage goes up and reaches V <sub>DESAT-THR</sub> , the output is driven low. Further, the /FLT output is activated, please refer to Figure 5 on page 10.<br><br>A 5 $\mu$ s mute time apply to IN+ and IN- once DESAT occurs. |
| GND2              | 3   | Power | Output side gate drive reference connecting to IGBT emitter or FET source.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| OUTH              | 4   | O     | Driver high output that provides the appropriate drive voltage and source current to the IGBT/FET gate.                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| V <sub>DD2</sub>  | 5   | Power | Output side positive power supply. The operating range for this pin is from UVLO2 to its maximum allowed value. A good quality bypassing capacitor is required from this pin to GND2 and should be placed close to the pins for best results.                                                                                                                                                                                                                                                                                                                        |
| OUTL              | 6   | O     | Driver low output that provides the appropriate drive voltage and sink current to the IGBT/FET gate. OUTL is actively pulled low during start-up and under Fault conditions.                                                                                                                                                                                                                                                                                                                                                                                         |
| CLAMP             | 7   | I/O   | Provides clamping for the IGBT/FET gate during the off period to protect it from parasitic turn-on. Its internal N FET is turned on when the voltage of this pin falls below V <sub>EE2</sub> + V <sub>CLAMP-THR</sub> . It is to be tied directly to IGBT/FET gate with minimum trace length for best results.                                                                                                                                                                                                                                                      |
| GND1A             | 9   | Power | Input side ground reference.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| GND1              | 16  |       |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| IN+               | 10  | I     | Non inverted gate driver input. It is internally clamped to V <sub>DD1</sub> and has a pull-down resistor of 50 k $\Omega$ to ensure that output is low in the absence of an input signal. A minimum positive going pulse-width is required at IN+ before OUTH/OUTL respond.                                                                                                                                                                                                                                                                                         |
| IN-               | 11  | I     | Inverted gate driver input. It is internally clamped to V <sub>DD1</sub> and has a pull-up resistor of 50 k $\Omega$ to ensure that output is low in the absence of an input signal. A minimum negative going pulse-width is required at IN- before OUTH/OUTL respond.                                                                                                                                                                                                                                                                                               |
| RDY               | 12  | O     | Power good indication output, active high when V <sub>DD1</sub> and V <sub>DD2</sub> are both good. There is an internal 50 k $\Omega$ pull-up resistor connected to this pin. Multiple of them from different drivers can be "OR"ed together.<br>OUTH/OUTL remain low when RDY is low. Short time delays may apply. See Figure 4 on page 9 for details.                                                                                                                                                                                                             |
| /FLT              | 13  | O     | Fault output (active low) that allows communication to the main controller that the driver has encountered a desaturation condition and has deactivated the output. There is an internal 50 k $\Omega$ pull-up resistor connected to this pin. Multiple of them from different drivers can be "OR"ed together.                                                                                                                                                                                                                                                       |
| /RST              | 14  | I     | Reset input with an internal 50 k $\Omega$ pull-up resistor, active low to reset fault latch.                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| V <sub>DD1</sub>  | 15  | Power | Input side power supply (3.3 V to 5 V).                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |

**SAFETY AND INSULATION RATINGS**

| Symbol                | Parameter                                                                                                                                                      | Value                   | Unit             |
|-----------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------|------------------|
|                       | Installation Classifications per DIN VDE 0110/1.89<br>Table 1 Rated Mains Voltage                                                                              | < 150 V <sub>RMS</sub>  | I – IV           |
|                       |                                                                                                                                                                | < 300 V <sub>RMS</sub>  | I – IV           |
|                       |                                                                                                                                                                | < 450 V <sub>RMS</sub>  | I – IV           |
|                       |                                                                                                                                                                | < 600 V <sub>RMS</sub>  | I – IV           |
|                       |                                                                                                                                                                | < 1000 V <sub>RMS</sub> | I – III          |
| CTI                   | Comparative Tracking Index (DIN IEC 112/VDE 0303 Part 1)                                                                                                       | 600                     |                  |
|                       | Climatic Classification                                                                                                                                        | 40/100/21               |                  |
|                       | Polution Degree (DIN VDE 0110/1.89)                                                                                                                            | 2                       |                  |
| V <sub>PR</sub>       | Input-to-Output Test Voltage, Method b, V <sub>IORM</sub> × 1.875 = V <sub>PR</sub> , 100% Production Test with t <sub>m</sub> = 1 s, Partial Discharge < 5 pC | 2250                    | V <sub>pk</sub>  |
|                       | Input-to-Output Test Voltage, Method a, V <sub>IORM</sub> × 1.6 = V <sub>PR</sub> , Type and Sample Test with t <sub>m</sub> = 10 s, Partial Discharge < 5 pC  | –                       | V <sub>pk</sub>  |
| V <sub>IORM</sub>     | Maximum Repetitive Peak Voltage                                                                                                                                | 1200                    | V <sub>pk</sub>  |
| V <sub>IOWM</sub>     | Maximum Working Insulation Voltage                                                                                                                             | 870                     | V <sub>RMS</sub> |
| V <sub>IOTM</sub>     | Highest Allowable Over Voltage                                                                                                                                 | 8400                    | V <sub>pk</sub>  |
| E <sub>CR</sub>       | External Creepage                                                                                                                                              | 8.0                     | mm               |
| E <sub>CL</sub>       | External Clearance                                                                                                                                             | 8.0                     | mm               |
| DTI                   | Insulation Thickness                                                                                                                                           | 17.3                    | um               |
| T <sub>Case</sub>     | Safety Limit Values – Maximum Values in Failure; Case Temperature                                                                                              | 150                     | °C               |
| P <sub>S,INPUT</sub>  | Safety Limit Values – Maximum Values in Failure; Input Power                                                                                                   | 36                      | mW               |
| P <sub>S,OUTPUT</sub> | Safety Limit Values – Maximum Values in Failure; Output Power                                                                                                  | 1364                    | mW               |
| R <sub>IO</sub>       | Insulation Resistance at TS, V <sub>IO</sub> = 500 V                                                                                                           | 10 <sup>9</sup>         | Ω                |

# NCV57000

## ABSOLUTE MAXIMUM RATINGS (Over operating free-air temperature range unless otherwise noted) (Note 1)

| Symbol                       | Parameter                                                                                                               | Minimum         | Maximum         | Unit         |
|------------------------------|-------------------------------------------------------------------------------------------------------------------------|-----------------|-----------------|--------------|
| $V_{DD1-GND1}$               | Supply voltage, input side                                                                                              | -0.3            | 6               | V            |
| $V_{DD2-GND2}$               | Positive Power Supply, output side                                                                                      | -0.3            | 25              | V            |
| $V_{EE2-GND2}$               | Negative Power Supply, output side                                                                                      | -10             | 0.3             | V            |
| $V_{DD2-V_{EE2}} (V_{MAX2})$ | Differential Power Supply, output side                                                                                  | 0               | 25              | V            |
| $V_{OUTH}$                   | Positive gate-driver output voltage                                                                                     | $V_{EE2} - 0.3$ | $V_{DD2} + 0.3$ | V            |
| $V_{OUTL}$                   | Negative gate-driver output voltage                                                                                     | $V_{EE2} - 0.3$ | $V_{DD2} + 0.3$ | V            |
| $I_{PK-SRC}$                 | Gate-driver output sourcing current<br>(maximum pulse width = 10 $\mu$ s, maximum duty cycle = 0.2%, $V_{MAX2} = 23$ V) | -               | 7.8             | A            |
| $I_{PK-SNK}$                 | Gate-driver output sinking current<br>(maximum pulse width = 10 $\mu$ s, maximum duty cycle = 0.2%, $V_{MAX2} = 23$ V)  | -               | 7.1             | A            |
| $I_{PK-CLAMP}$               | Clamp sinking current<br>(maximum pulse width = 10 $\mu$ s, maximum duty cycle = 0.2%, $V_{CLAMP} = 2.5$ V)             | -               | 2.5             | A            |
| $t_{CLP}$                    | Maximum Short Circuit Clamping Time ( $I_{OUTH\_CLAMP} = 500$ mA)                                                       | -               | 10              | $\mu$ s      |
| $V_{LIM-GND1}$               | Voltage at IN+, IN-, /RST, /FLT, RDY                                                                                    | -0.3            | $V_{DD1} + 0.3$ | V            |
| $I_{LIM-GND1}$               | Output current of /FLT, RDY                                                                                             | -               | 10              | mA           |
| $V_{DESAT-GND2}$             | Desat Voltage (Note 2)                                                                                                  | -9              | $V_{DD2} + 0.3$ | V            |
| $V_{CLAMP-GND2}$             | Clamp Voltage                                                                                                           | $V_{EE2} - 0.3$ | $V_{DD2} + 0.3$ | V            |
| $P_D$                        | Power Dissipation (Note 3)                                                                                              | -               | 1400            | mW           |
| $T_{J(max)}$                 | Maximum Junction Temperature                                                                                            | -40             | 150             | $^{\circ}$ C |
| $T_{STG}$                    | Storage Temperature Range                                                                                               | -65             | 150             | $^{\circ}$ C |
| $ESD_{HBM}$                  | ESD Capability, Human Body Model (Note 4)                                                                               | -               | $\pm 2$         | kV           |
| $ESD_{CDM}$                  | ESD Capability, Charged Device Model (Note 4)                                                                           | -               | $\pm 2$         | kV           |
| MSL                          | Moisture Sensitivity Level                                                                                              | -               | 2               | -            |
| $T_{SLD}$                    | Lead Temperature Soldering Reflow, Pb-Free Versions (Note 5)                                                            | -               | 260             | $^{\circ}$ C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
2. The minimum value is verified by characterization with a single pulse of 100 mA for 100  $\mu$ s.
3. The value is estimated for ambient temperature 25 $^{\circ}$ C and junction temperature 150 $^{\circ}$ C, 650 mm<sup>2</sup>, 1 oz copper, 2 surface layers and 2 internal power plane layers. Power dissipation is affected by the PCB design and ambient temperature.
4. This device series incorporates ESD protection and is tested by the following methods:  
 ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)  
 ESD Charged Device Model tested per AEC-Q100-011 (EIA/JESD22-C101)  
 Latchup Current Maximum Rating:  $\leq 100$  mA per JEDEC standard: JESD78, 125 $^{\circ}$ C
5. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

## THERMAL CHARACTERISTICS

| Symbol          | Parameter                           | Conditions                                                                            | Value | Unit           |
|-----------------|-------------------------------------|---------------------------------------------------------------------------------------|-------|----------------|
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Air | 100 mm <sup>2</sup> , 1 oz Copper, 1 Surface Layer                                    | 114   | $^{\circ}$ C/W |
|                 |                                     | 650 mm <sup>2</sup> , 1 oz Copper, 2 Surface Layers and 2 Internal Power Plane Layers | 62    |                |

**OPERATING RANGES** (Note 6)

| Symbol                                                  | Parameter                                  | Min                    | Max                    | Unit  |
|---------------------------------------------------------|--------------------------------------------|------------------------|------------------------|-------|
| V <sub>DD1</sub> -GND1                                  | Supply voltage, input side                 | UVLO1                  | 5.5                    | V     |
| V <sub>DD2</sub> -GND2                                  | Positive Power Supply, output side         | UVLO2                  | 24                     | V     |
| V <sub>EE2</sub> -GND2                                  | Negative Power Supply, output side         | -10                    | 0                      | V     |
| V <sub>DD2</sub> -V <sub>EE2</sub> (V <sub>MAX2</sub> ) | Differential Power Supply, output side     | 0                      | 24                     | V     |
| V <sub>IL</sub>                                         | Low level input voltage at IN+, IN-, /RST  | 0                      | 0.3 X V <sub>DD1</sub> | V     |
| V <sub>IH</sub>                                         | High level input voltage at IN+, IN-, /RST | 0.7 X V <sub>DD1</sub> | V <sub>DD1</sub>       | V     |
| dV <sub>ISO</sub> /dt                                   | Common Mode Transient Immunity             | 100                    | -                      | kV/μs |
| T <sub>A</sub>                                          | Ambient Temperature                        | -40                    | 125                    | °C    |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

**ISOLATION CHARACTERISTICS**

| Symbol                         | Parameter                      | Conditions                                                                                                      | Min  | Typ              | Max | Unit             |
|--------------------------------|--------------------------------|-----------------------------------------------------------------------------------------------------------------|------|------------------|-----|------------------|
| V <sub>ISO, input-output</sub> | Input-Output Isolation Voltage | T <sub>A</sub> = 25°C, Relative Humidity < 50%, t = 1.0 minute, I <sub>I-O</sub> 10 A, 50 Hz (See Note 7, 8, 9) | 5000 | -                | -   | V <sub>RMS</sub> |
| R <sub>ISO</sub>               | Isolation Resistance           | V <sub>I-O</sub> = 500 V (See Note 7)                                                                           | -    | 10 <sup>11</sup> | -   | Ω                |

7. Device is considered a two-terminal device: pins 1 to 8 are shorted together and pins 9 to 16 are shorted together

8. 5,000 V<sub>RMS</sub> for 1-minute duration is equivalent to 6,000 V<sub>RMS</sub> for 1-second duration.

9. The input-output isolation voltage is a dielectric voltage rating per UL1577. It should not be regarded as an input-output continuous voltage rating. For the continuous working voltage rating, refer to equipment-level safety specification or DIN VDE V 0884-11 Safety and Insulation Ratings Table

**ELECTRICAL CHARACTERISTICS** (V<sub>DD1</sub> = 5 V, V<sub>DD2</sub> = 15 V, V<sub>EE2</sub> = -8 V. For typical values T<sub>A</sub> = 25°C, for min/max values, T<sub>A</sub> is the operating ambient temperature range that applies, unless otherwise noted)

| Symbol | Parameter | Test Condition | Min | Typ | Max | Unit |
|--------|-----------|----------------|-----|-----|-----|------|
|--------|-----------|----------------|-----|-----|-----|------|

**VOLTAGE SUPPLY**

|                             |                                                       |                                  |       |      |      |    |
|-----------------------------|-------------------------------------------------------|----------------------------------|-------|------|------|----|
| V <sub>UVLO1</sub> -OUT-ON  | UVLO1 Output Enabled                                  |                                  | -     | -    | 3.05 | V  |
| V <sub>UVLO1</sub> -OUT-OFF | UVLO1 Output Disabled                                 |                                  | 2.4   | -    | -    | V  |
| V <sub>UVLO1</sub> -HYST    | UVLO1 Hysteresis                                      |                                  | 0.125 | -    | -    | V  |
| V <sub>UVLO2</sub> -OUT-ON  | UVLO2 Output Enabled                                  |                                  | 13.2  | 13.5 | 13.8 | V  |
| V <sub>UVLO2</sub> -OUT-OFF | UVLO2 Output Disabled                                 |                                  | 12.2  | 12.5 | 12.8 | V  |
| V <sub>UVLO2</sub> -HYST    | UVLO2 Hysteresis                                      |                                  | -     | 1    |      | V  |
| I <sub>DD1</sub> -0         | Input Supply Quiescent Current Output Low             | IN+ = Low, IN- = Low             | -     | 1    | 2    | mA |
|                             |                                                       | RDY = High, /FLT = High          |       |      |      |    |
| I <sub>DD1</sub> -100       | Input Supply Quiescent Current Output High            | IN+ = High, IN- = Low            | -     | 4.8  | 6    | mA |
|                             |                                                       | RDY = High, /FLT = High          |       |      |      |    |
| I <sub>DD2</sub> -0         | Output Positive Supply Quiescent Current, Output Low  | IN+ = Low, IN- = Low             | -     | 3.3  | 4    | mA |
|                             |                                                       | RDY = High, /FLT = High, no load |       |      |      |    |
| I <sub>DD2</sub> -100       | Output Positive Supply Quiescent Current, Output High | IN+ = High, IN- = Low            | -     | 3.6  | 4    | mA |
|                             |                                                       | RDY = High, /FLT = High, no load |       |      |      |    |
| I <sub>EE2</sub> -0         | Output Negative Supply Quiescent Current, Output Low  | IN+ = High, IN- = Low, no load   | -     | 0.4  | 2    | mA |
| I <sub>EE2</sub> -100       | Output Negative Supply Quiescent Current, Output High | IN+ = High, IN- = Low, no load   | -     | 0.2  | 2    | mA |

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**ELECTRICAL CHARACTERISTICS** ( $V_{DD1} = 5\text{ V}$ ,  $V_{DD2} = 15\text{ V}$ ,  $V_{EE2} = -8\text{ V}$ . For typical values  $T_A = 25^\circ\text{C}$ , for min/max values,  $T_A$  is the operating ambient temperature range that applies, unless otherwise noted) (continued)

| Symbol | Parameter | Test Condition | Min | Typ | Max | Unit |
|--------|-----------|----------------|-----|-----|-----|------|
|--------|-----------|----------------|-----|-----|-----|------|

## LOGIC INPUT AND OUTPUT

|                        |                                                                 |                                 |                      |                       |                      |               |
|------------------------|-----------------------------------------------------------------|---------------------------------|----------------------|-----------------------|----------------------|---------------|
| $V_{IL}$               | IN+, IN-, /RST Low Input Voltage                                |                                 | –                    | –                     | $0.3 \times V_{DD1}$ | V             |
| $V_{IH}$               | IN+, IN-, /RST High Input Voltage                               |                                 | $0.7 \times V_{DD1}$ | –                     | –                    | V             |
| $V_{IN-HYST}$          | Input Hysteresis Voltage                                        |                                 | –                    | $0.15 \times V_{DD1}$ | –                    | V             |
| $I_{IN-L}, I_{RST-L}$  | IN-, /RST Input Current (50 k $\Omega$ pull-up resistor)        | $V_{IN-}/V_{RST} = 0\text{ V}$  | –                    | –100                  | –                    | $\mu\text{A}$ |
| $I_{IN+H}$             | IN+ Input Current (50 k $\Omega$ pull-down resistor)            | $V_{IN+} = 5\text{ V}$          | –                    | 100                   | –                    | $\mu\text{A}$ |
| $I_{RDY-L}, I_{FLT-L}$ | RDY, /FLT Pull-up Current (50 k $\Omega$ pull-up resistor)      | $V_{RDY}/V_{FLT} = \text{Low}$  | –                    | 100                   | –                    | $\mu\text{A}$ |
| $V_{RDY-L}, V_{FLT-L}$ | RDY, /FLT Low Level Output Voltage                              | $I_{RDY}/I_{FLT} = 5\text{ mA}$ | –                    | –                     | 0.3                  | V             |
| $t_{MIN1}$             | Input Pulse Width of IN+, IN- for No Response at Output         |                                 | –                    | –                     | 10                   | ns            |
| $t_{MIN2}$             | Input Pulse Width of IN+, IN- for Guaranteed Response at Output |                                 | 40                   | –                     | –                    | ns            |
| $t_{RST-MIN}$          | Pulse Width of /RST for Resetting /FLT                          |                                 | 800                  | –                     | –                    | ns            |

## DRIVER OUTPUT

|               |                                            |                                                      |   |     |     |   |
|---------------|--------------------------------------------|------------------------------------------------------|---|-----|-----|---|
| $V_{OUTL1}$   | Output Low State ( $V_{OUTL} - V_{EE2}$ )  | $I_{SINK} = 200\text{ mA}$                           | – | 0.1 | 0.2 | V |
| $V_{OUTL3}$   |                                            | $I_{SINK} = 1.0\text{ A}$ , $T_A = 25^\circ\text{C}$ | – | 0.5 | 0.8 |   |
| $V_{OUTH1}$   | Output High State ( $V_{DD2} - V_{OUTH}$ ) | $I_{SRC} = 200\text{ mA}$                            | – | 0.3 | 0.5 | V |
| $V_{OUTH3}$   |                                            | $I_{SRC} = 1.0\text{ A}$ , $T_A = 25^\circ\text{C}$  | – | 0.8 | 1   |   |
| $I_{PK-SNK1}$ | Peak Driver Current, Sink (Note 10)        | $V_{OUTH} = 7.9\text{ V}$                            | – | 7.1 | –   | A |
| $I_{PK-SRC1}$ | Peak Driver Current, Source (Note 10)      | $V_{OUTL} = -5\text{ V}$                             | – | 7.8 | –   | A |

## MILLER CLAMP

|                 |                                                      |                                                                               |     |     |     |   |
|-----------------|------------------------------------------------------|-------------------------------------------------------------------------------|-----|-----|-----|---|
| $V_{CLAMP}$     | Clamp Voltage ( $V_{CLAMP} - V_{EE2}$ )              | $I_{CLAMP} = 2.5\text{ A}$ , $T_A = 25^\circ\text{C}$                         | –   | 1.3 | 1.7 | V |
|                 |                                                      | $I_{CLAMP} = 2.5\text{ A}$ , $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$ | –   | –   | 2.7 |   |
| $V_{CLAMP-THR}$ | Clamp Activation Threshold ( $V_{CLAMP} - V_{EE2}$ ) |                                                                               | 1.5 | 2   | 2.5 | V |

## IGBT SHORT CIRCUIT CLAMPING

|                   |                                                     |                                                                                                              |   |     |     |   |
|-------------------|-----------------------------------------------------|--------------------------------------------------------------------------------------------------------------|---|-----|-----|---|
| $V_{CLAMP-OUTH}$  | Clamping Voltage, Sourcing ( $V_{OUTH} - V_{DD2}$ ) | IN+ = Low, IN- = High, $I_{CLAMP-OUTH} = 500\text{ mA}$ (pulse test, $t_{CLPmax} = 10\text{ }\mu\text{s}$ )  | – | 0.9 | 1   | V |
| $V_{CLAMP-OUTL}$  | Clamping Voltage, Sinking ( $V_{OUTL} - V_{DD2}$ )  | IN+ = High, IN- = Low, $I_{CLAMP-OUTL} = 500\text{ mA}$ (pulse test, $t_{CLPmax} = 10\text{ }\mu\text{s}$ )  | – | 1.2 | 1.5 | V |
| $V_{CLAMP-CLAMP}$ | Clamping Voltage, Clamp ( $V_{CLAMP} - V_{DD2}$ )   | IN+ = High, IN- = Low, $I_{CLAMP-CLAMP} = 500\text{ mA}$ (pulse test, $t_{CLPmax} = 10\text{ }\mu\text{s}$ ) | – | 1.4 | 1.6 | V |

## DESAT PROTECTION

|                 |                            |                             |      |     |     |    |
|-----------------|----------------------------|-----------------------------|------|-----|-----|----|
| $V_{DESAT-THR}$ | DESAT Threshold Voltage    |                             | 8.5  | 9   | 9.5 | V  |
| $V_{DESAT-NEG}$ | DESAT Negative Voltage     | $I_{DESAT} = 1.5\text{ mA}$ | –    | –8  | –   | V  |
| $I_{DESAT-CHG}$ | Blanking Charge Current    | $V_{DESAT} = 7\text{ V}$    | 0.45 | 0.5 | 0.6 | mA |
| $I_{DESAT-DIS}$ | Blanking Discharge Current |                             | –    | 50  | –   | mA |

# NCV57000

**ELECTRICAL CHARACTERISTICS** ( $V_{DD1} = 5\text{ V}$ ,  $V_{DD2} = 15\text{ V}$ ,  $V_{EE2} = -8\text{ V}$ . For typical values  $T_A = 25^\circ\text{C}$ , for min/max values,  $T_A$  is the operating ambient temperature range that applies, unless otherwise noted) (continued)

| Symbol                         | Parameter                                                     | Test Condition                                                                                                                                  | Min | Typ | Max | Unit          |
|--------------------------------|---------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|
| <b>DYNAMIC CHARACTERISTICS</b> |                                                               |                                                                                                                                                 |     |     |     |               |
| $t_{PD-ON}$                    | IN+, IN- to Output High Propagation Delay                     | $C_{LOAD} = 10\text{ nF}$<br>$V_{IH}$ to 10% of output change for<br>$PW > 150\text{ ns}$ . OUTH, OUTL and<br>CLAMP pins are connected together | 40  | 60  | 90  | ns            |
| $t_{PD-OFF}$                   | IN+, IN- to Output Low Propagation Delay                      | $C_{LOAD} = 10\text{ nF}$<br>$V_{IL}$ to 90% of output change for<br>$PW > 150\text{ ns}$ . OUTH, OUTL and<br>CLAMP pins are connected together | 40  | 66  | 90  | ns            |
| $t_{DISTORT}$                  | Propagation Delay Distortion<br>(= $t_{PD-ON} - t_{PD-OFF}$ ) | $T_A = 25^\circ\text{C}$ , $PW > 150\text{ ns}$                                                                                                 | -15 | -6  | 15  | ns            |
|                                |                                                               | $T_A = -40^\circ\text{C}$ to $125^\circ\text{C}$ , $PW > 150\text{ ns}$                                                                         | -25 | -   | 25  |               |
| $t_{DISTORT\_TOT}$             | Prop Delay Distortion between Parts                           | $PW > 150\text{ ns}$                                                                                                                            | -30 | 0   | 30  | ns            |
| $t_{RISE}$                     | Rise Time (see Fig. 3) (Note 10)                              | $C_{LOAD} = 1\text{ nF}$ , 10% to 90% of<br>Output Change                                                                                       | -   | 10  | -   | ns            |
| $t_{FALL}$                     | Fall Time (see Fig. 3) (Note 10)                              | $C_{LOAD} = 1\text{ nF}$ , 90% to 10% of<br>Output Change                                                                                       | -   | 15  | -   | ns            |
| $t_{LEB}$                      | DESAT Leading Edge Blanking Time<br>(See Fig. 5)              |                                                                                                                                                 | -   | 450 | -   | ns            |
| $t_{FILTER}$                   | DESAT Threshold Filtering Time<br>(see Fig. 5)                |                                                                                                                                                 | -   | 320 | -   | ns            |
| $t_{STO}$                      | Soft Turn Off Time (see Fig. 5)                               | $C_{LOAD} = 10\text{ nF}$ , $R_G = 10\ \Omega$ , $V_{EE2} = 0\text{ V}$                                                                         | -   | 1.8 | -   | $\mu\text{s}$ |
|                                |                                                               | $C_{LOAD} = 10\text{ nF}$ , $R_G = 10\ \Omega$                                                                                                  | -   | 2.6 | -   |               |
| $t_{FLT}$                      | Delay after $t_{FILTER}$ to /FLT                              |                                                                                                                                                 | -   | 450 | -   | ns            |
| $t_{RST}$                      | /RST Rise to /FLT Rise Delay                                  |                                                                                                                                                 | -   | 23  | -   | ns            |
| $t_{RDY1O}$                    | RDY High to Output High Delays<br>(see Fig. 4)                |                                                                                                                                                 | -   | 55  | -   | ns            |
| $t_{RDY2O}$                    |                                                               |                                                                                                                                                 |     |     |     |               |
| $t_{RDY1F}$                    | $V_{UVLO2-OUT-OFF}$ to RDY Low<br>Delays (see Fig. 4)         |                                                                                                                                                 | -   | 8   | -   | $\mu\text{s}$ |
| $t_{RDY2F}$                    |                                                               |                                                                                                                                                 |     |     |     |               |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

10. Values based on design and/or characterization.

## ORDERING INFORMATION

| Device        | Package Type                   | Shipping <sup>†</sup> |
|---------------|--------------------------------|-----------------------|
| NCV57000DWR2G | SOIC-16 Wide Body<br>(Pb-Free) | 1,000 / Tape & Reel   |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



# NCV57000

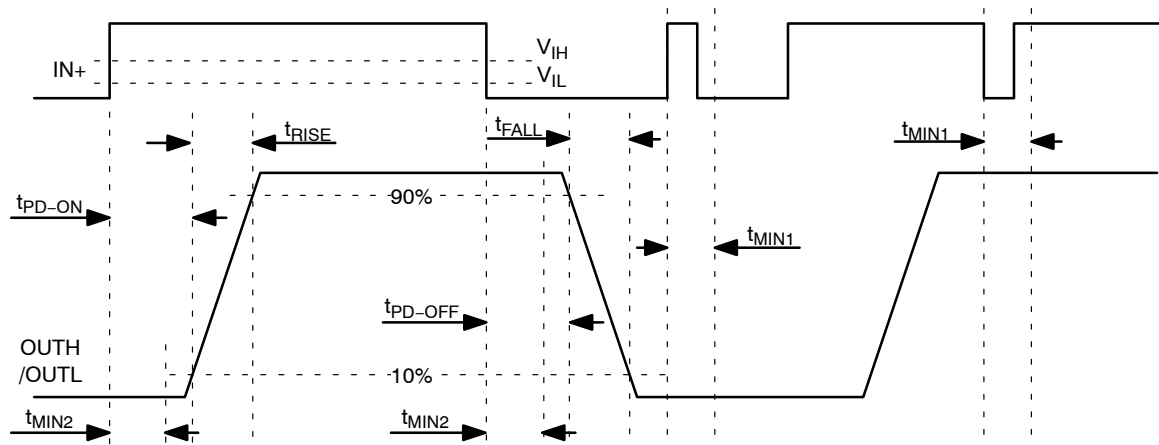


Figure 3. Propagation Delay, Rise and Fall Time

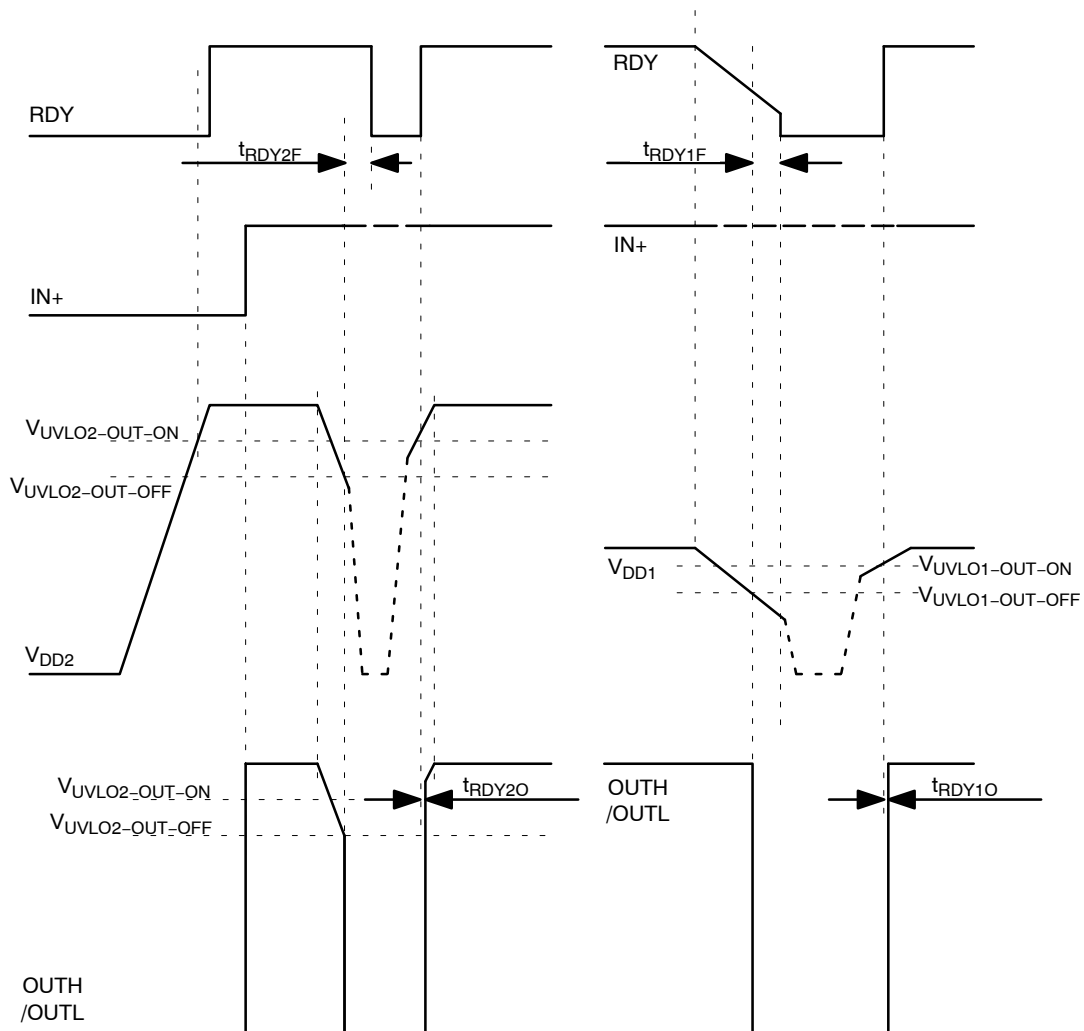


Figure 4. UVLO Waveform

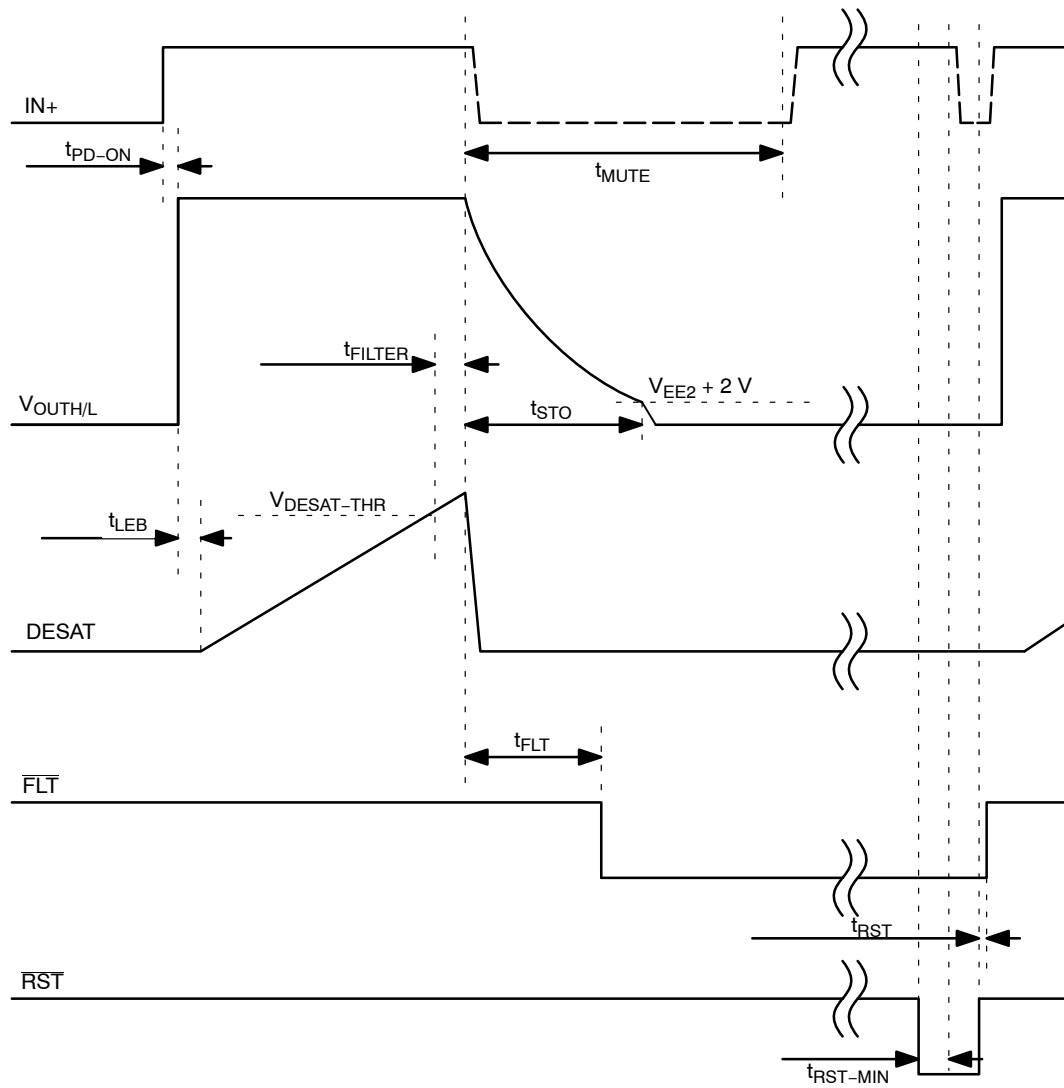


Figure 5. DESAT Response Waveform

# TYPICAL CHARACTERISTICS

(Conditions for the following figures are the same as stated for ELECTRICAL CHARACTERISTICS Table unless otherwise noted.  
Typical and/or average values are used.)

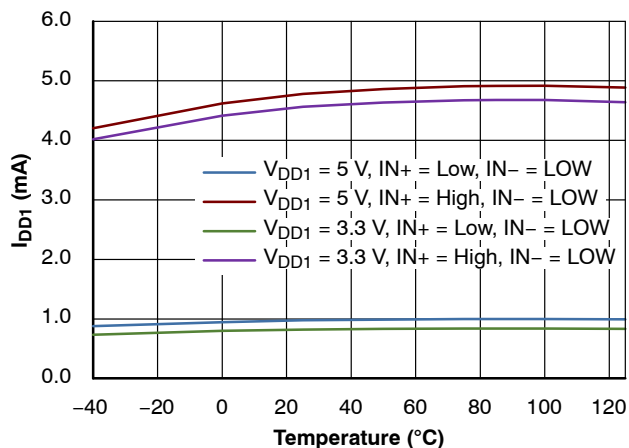


Figure 6.  $V_{DD1}$  Supply Current

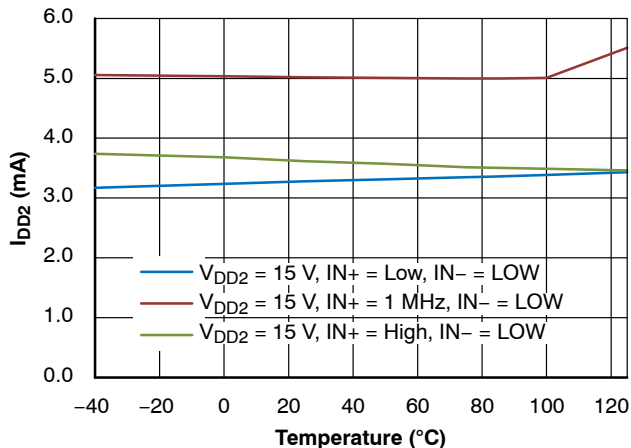


Figure 7.  $V_{DD2}$  Supply Current

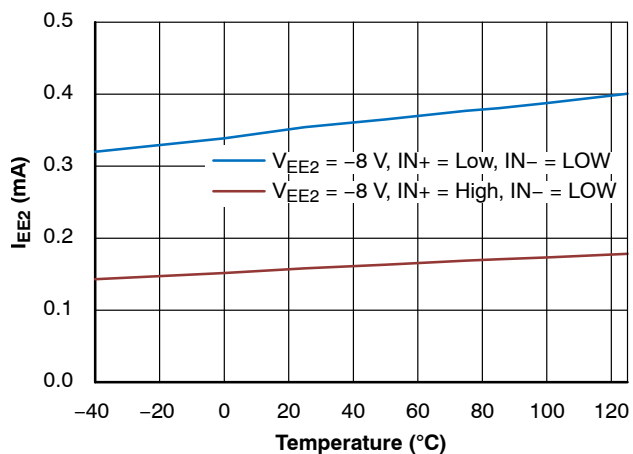


Figure 8.  $V_{EE2}$  Supply Current

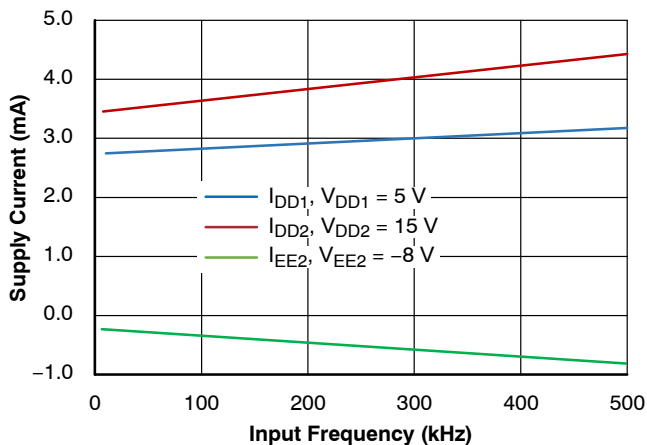


Figure 9. Supply Current vs Frequency

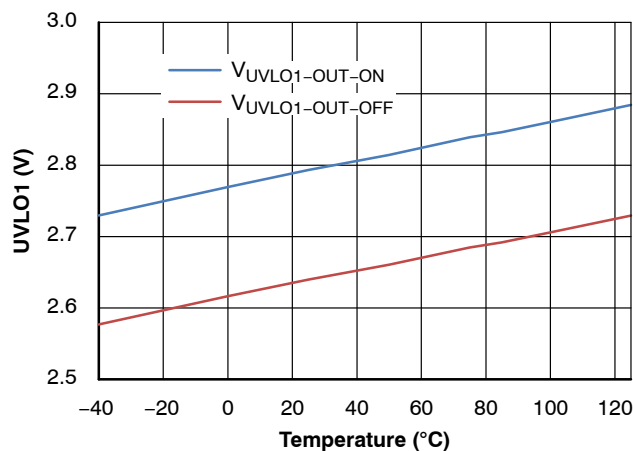


Figure 10. UVLO1 Threshold Voltage

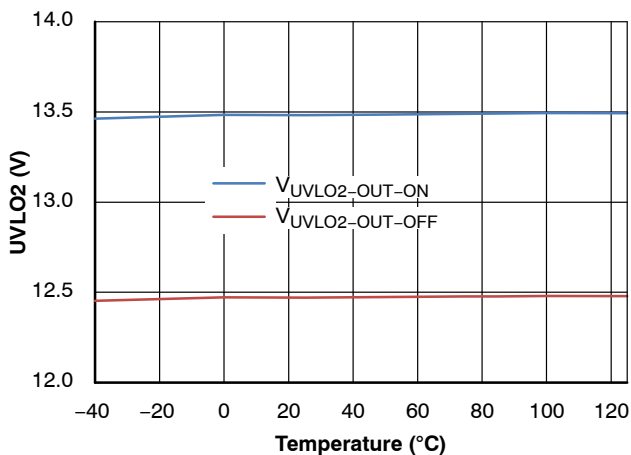


Figure 11. UVLO2 Threshold Voltage

# TYPICAL CHARACTERISTICS

(Conditions for the following figures are the same as stated for ELECTRICAL CHARACTERISTICS Table unless otherwise noted.  
Typical and/or average values are used.) (continued)

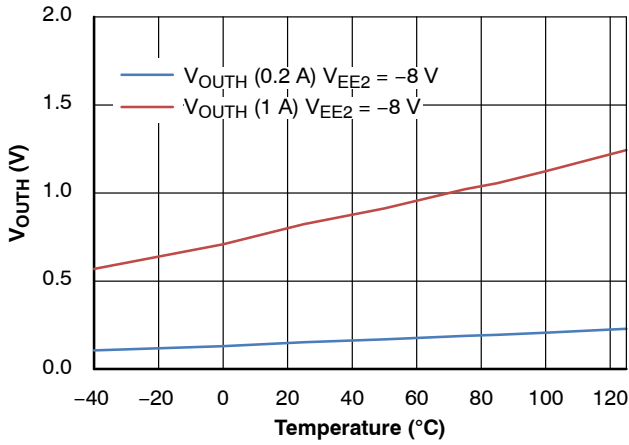


Figure 12. Output Voltage Drop, Sourcing

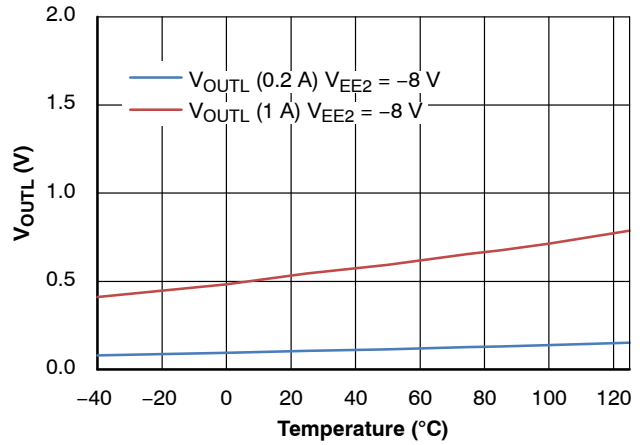


Figure 13. Output Voltage Drop, Sinking

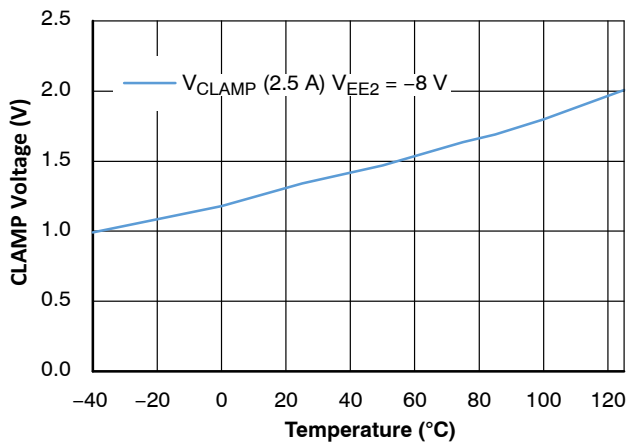


Figure 14. CLAMP Voltage Drop

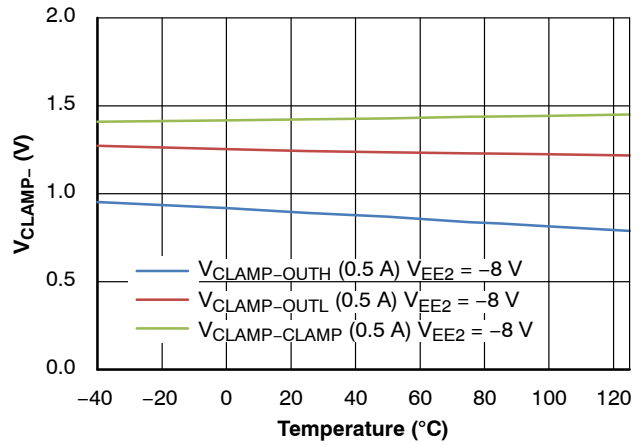


Figure 15. IGBT Short Circuit Clamp Voltage Drop

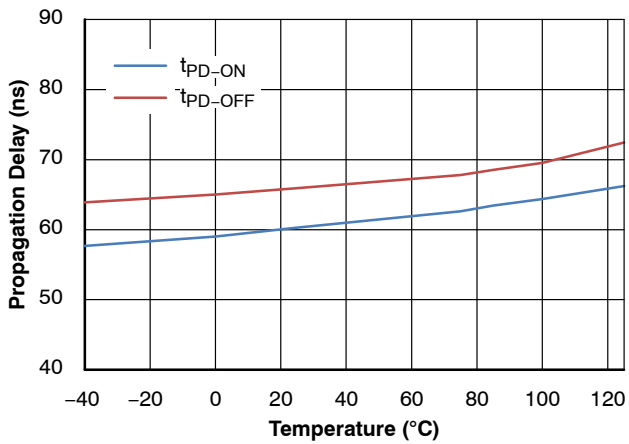


Figure 16. Propagation Delay

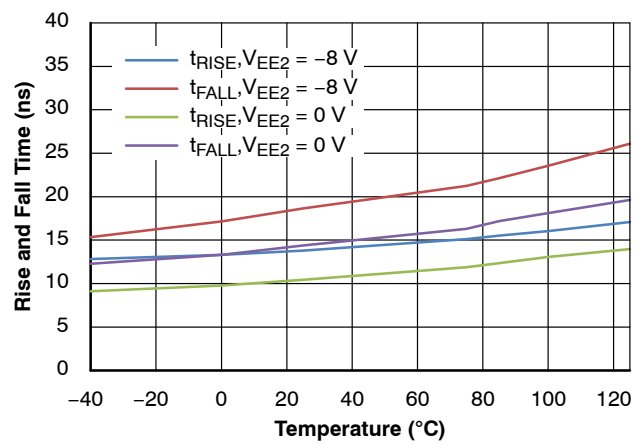


Figure 17. Rise and Fall Time

# NCV57000

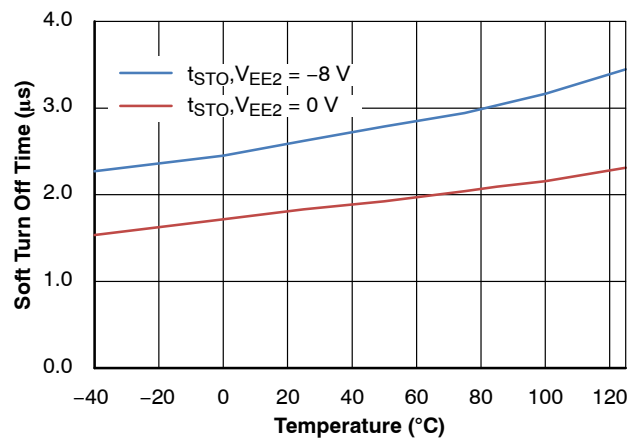


Figure 18. Soft Turn Off Time

## FEATURE DESCRIPTIONS

### Under Voltage Lockout (UVLO)

UVLO ensures correct switching of IGBT connected to the driver output.

- The IGBT is turned-off, if the supply  $V_{CC1}$  drops below  $V_{UVLO1-OUT-OFF}$  and the RDY pin output goes to low.
- The driver output does not start to react to the input signal on  $V_{IN}$  until the  $V_{CC1}$  rises above the  $V_{UVLO1-OUT-ON}$  again. If the supply  $V_{CC1}$  increase over  $V_{UVLO1-OUT-ON}$ , the RDY pin output goes to be open-drain and outputs continue to switch IGBT

- The IGBT is turned-off, if the supply  $V_{CC2}$  drops below  $V_{UVLO2-OUT-OFF}$  and the RDY pin output goes to low.
- The driver output does not start to react to the input signal on  $V_{IN}$  until the  $V_{CC1}$  rises above the  $V_{UVLO1-OUT-ON}$  again. If the supply  $V_{DD1}$  increases over  $V_{UVLO1-OUT-ON}$ , the RDY pin output goes to be open-drain and outputs continue to switch IGBT
- VEE2 is not monitored.

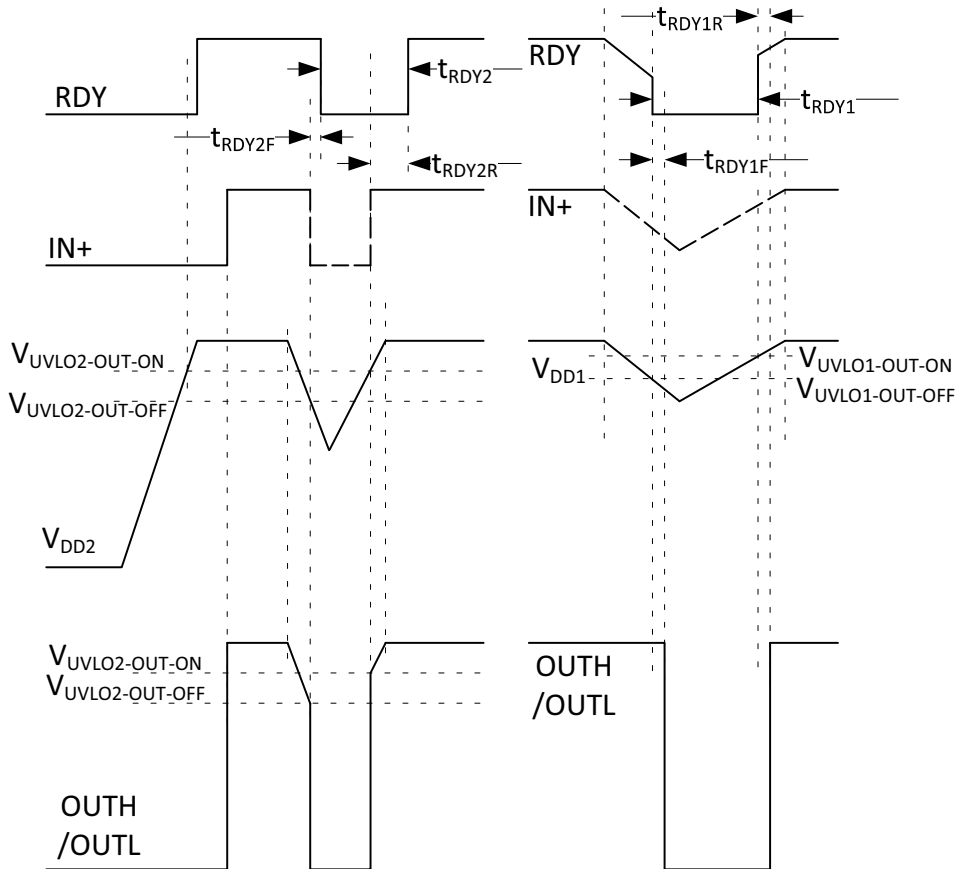


Figure 19. UVLO Diagram

### Active Miller Clamp Protection (CLAMP)

NCV57000 supports both bipolar and unipolar power supply with active Miller clamp.

For operation with bipolar supplies, the IGBT is turned off with a negative voltage through OUTL with respect to its emitter. This prevents the IGBT from unintentionally turning on because of current induced from its collector to its gate due to Miller effect. In this condition it is not necessary to connect CLAMP output of the gate driver to the IGBT gate, but connecting CLAMP output to the IGBT gate is also not an issue. Typical values for bipolar operation are  $V_{DD2} = 15\text{ V}$  and  $V_{EE2} = -5\text{ V}$  with respect to  $GND_2$ .

For operation with unipolar supply, typically,  $V_{DD2} = 15\text{ V}$  with respect to  $GND_2$ , and  $V_{EE2} = GND_2$ . In this case, the IGBT can turn on due to additional charge from IGBT Miller capacitance caused by a high voltage slew rate transition on the IGBT collector. To prevent IGBT to turn on, the CLAMP pin is connected directly to IGBT gate and Miller current is sunk through a low impedance CLAMP transistor. When the IGBT is turned-off and the gate voltage transitions below  $V_{CLAMP}$ , the CLAMP current output is activated.

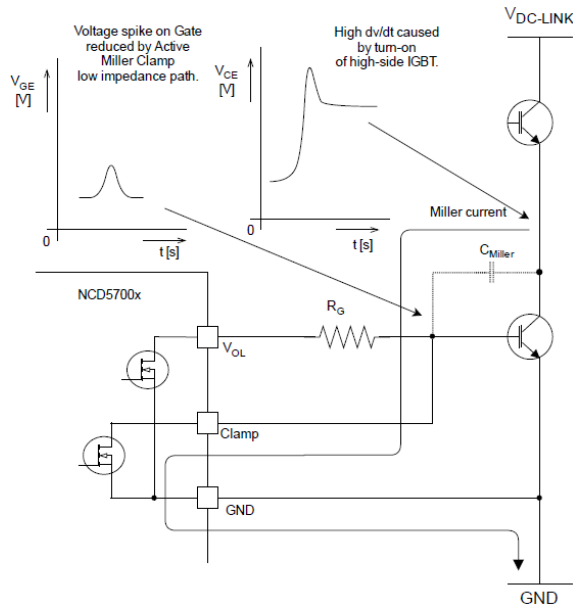


Figure 20. Current Path without Miler Clamp Protection

#### Non-inverting and Inverting Input Pin (IN+, IN-)

NCV57000 has two possible input modes to control IGBT. Both inputs have defined minimum input pulse width to filter occasional glitches.

- Non-inverting input IN+ controls the driver output while inverting input IN- is set to LOW
- Inverting input IN- controls the driver output while non-inverting input IN+ is set to HIGH

**Warning:** When the application use an independent or separate power supply for the control unit ant the input side of the driver, all inputs should be protected by a serial resistor (In case of a power failure of the driver, the driver may be damaged due to overloading of the input protection circuits)

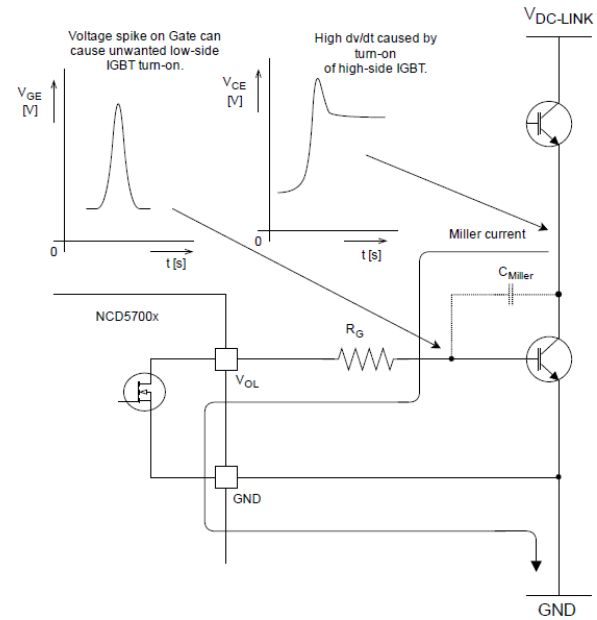


Figure 21. Current Path with Miler Clamp Protection

#### Desaturation Protection (DESAT)

Desaturation protection ensures the protection of IGBT at short circuit. When the  $V_{CESAT}$  voltage goes up and reaches the set limit, the output is driven low and /FLT output is activated. Blanking time can be set by internal current source and an external capacitor. To avoid false DESAT triggering and minimize blanking time, fast switching diodes with low internal capacitance are recommended. All DESAT protective diodes internal capacitances builds voltage divider with the blanking capacitor.

**Warning:** Both external protective diodes are recommended for the protection against voltage spikes caused by IGBT transients passing through parasitic capacitances.

#### DESAT Circuit Parameters Specification

$$t_{BLANK} = C_{BLANK} \cdot \frac{V_{DESAT-THR}}{I_{DESAT-CHG}}$$

$$V_{DESAT-THR} > R_{S-DESAT} \cdot I_{DESAT-CHG} + V_{FHV diode} + V_{CESAT\_IGBT}$$

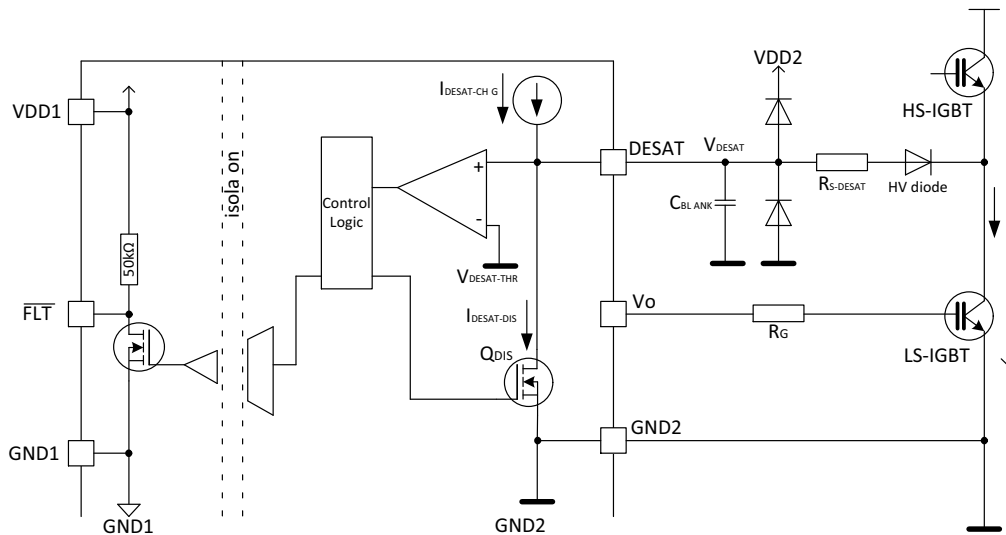


Figure 22. DESAT Protection Schematic

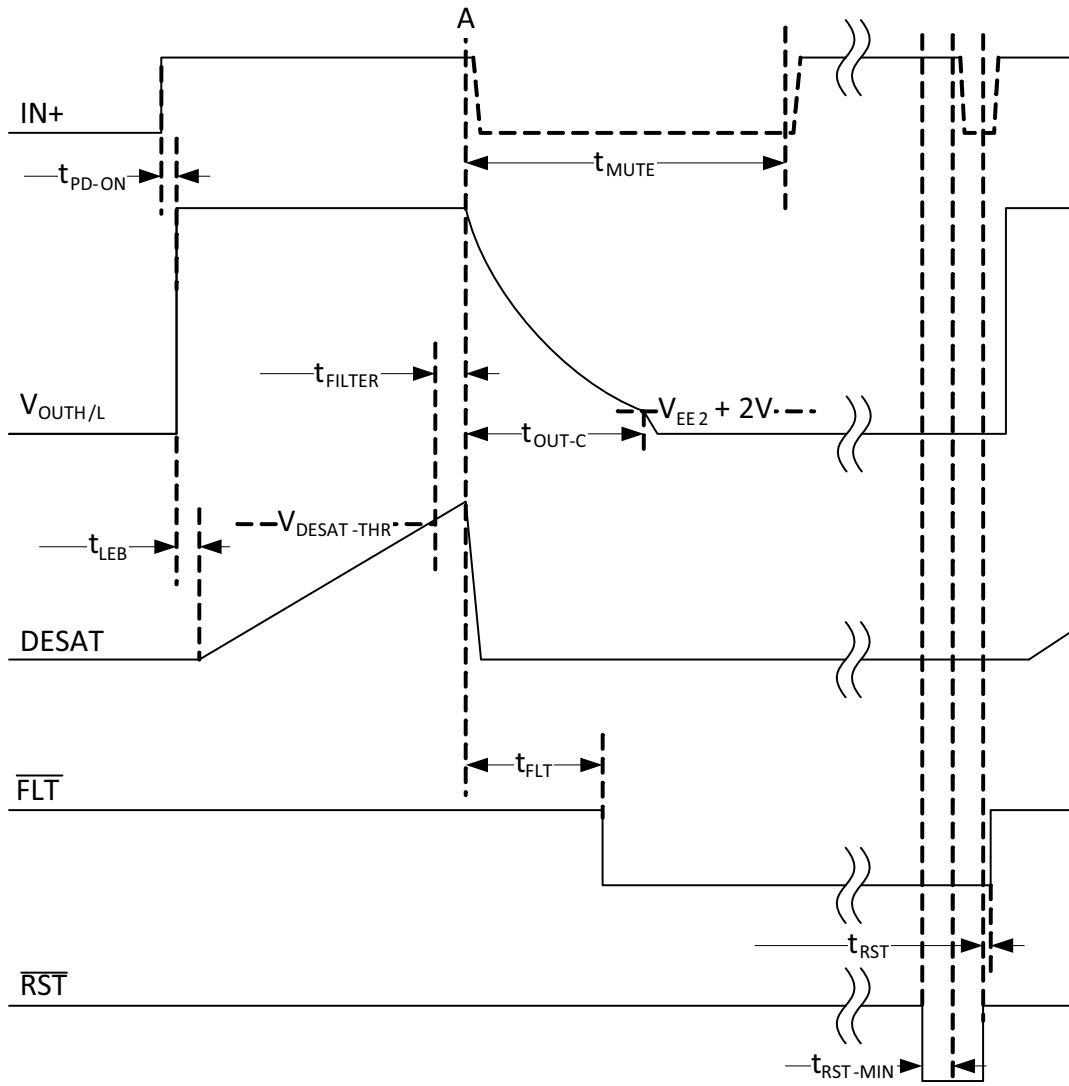


Figure 23. DESAT Switch Off Behavior



### Fault Output Pin (FLT)

FLT open-drain output provides feedback to the controller about driver DESAT protection conditions. The open-drain FLT outputs of multiple NCV57000 devices can be wired together forming a single, common fault bus for interfacing directly to the microcontroller. FLT output has 50k $\Omega$  internal pull-up resistor to VDD1.

### Ready Output Pin (RDY)

RDY open-drain output provides feedback to the controller about driver UVLO and TSD protections conditions.

- If either side of device have insufficient supply (VDD1 or VDD2), the RDY pin output goes low; otherwise, RDY pin output is open drain.
- If the temperature crosses the TSD threshold, the RDY pin output goes low; otherwise, RDY pin output is open drain.

The open-drain RDY outputs of multiple NCV57000 devices can be "OR"ed together.

### Reset Input Pin (RST)

Reset input pin has internal pull-up resistor to VDD1. In normal condition the RST pin is connected to HIGH, to reset FAULT conditions connect RST pin to LOW. In applications that does not allow to control the reset, RST pin should be connected to IN+, the driver will be reset by each input pulse.

### RESET Input

- FLT input is used to set back FLT output after DESAT conditions disappear

**Warning:** When the application use an independent or separate power supply for the control unit ant the input side of the driver, all inputs should be protected by a serial resistor (In case of a power failure of the driver, the driver may be damaged due to overloading of the input protection circuits)

### Power Supply (VDD1, VDD2, VEE2)

NCV57000 is designed to support two different power supply configurations, bipolar or unipolar power supply. For reliable high output current the suitable external power capacitors required. Parallel combination of 100 nF + 4.7  $\mu$ F ceramic capacitors is optimal for a wide range of applications using IGBT. For reliable driving IGBT modules (containing several parallel IGBT's) is a higher capacity required (typically 100 nF + 10  $\mu$ F). Capacitors should be as close as possible to the driver's power pins.

- In bipolar power supply the driver is typically supplied with a positive voltage of 15 V at VDD2 and negative voltage -5 V at VEE2 (Figure 24). Negative power supply prevents a dynamic turn on throughout the internal IGBT input capacitance.
- In Unipolar power supply the driver is typically supplied with a positive voltage of 15 V at VDD2. Dynamic turn on throughout the internal IGBT input capacitance could be prevented by Active Miller Clamp function. CLAMP output should be directly connected to IGBT gate (Figure 25).

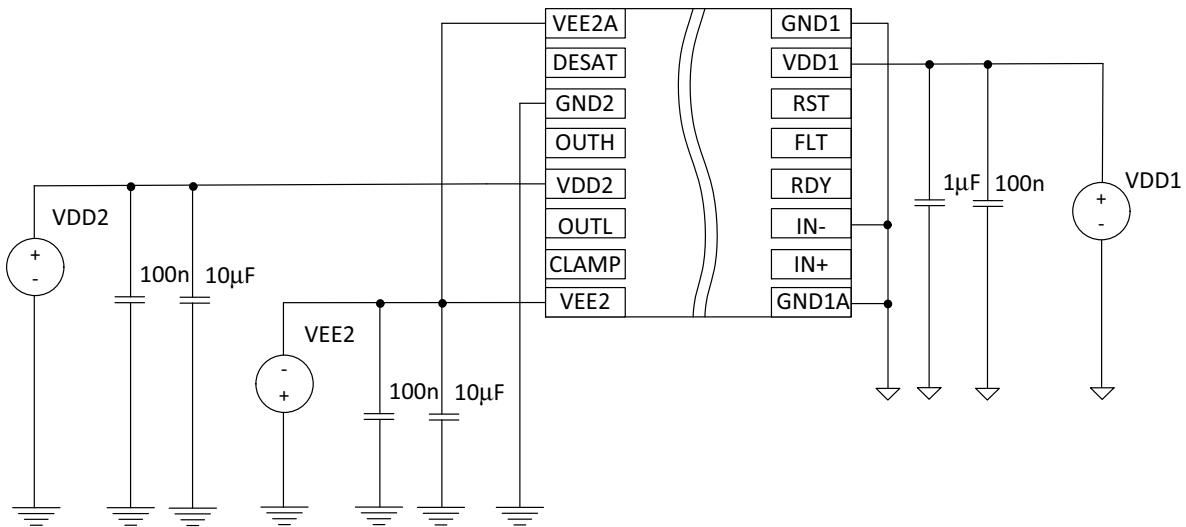


Figure 24. Bipolar Power Supply

## NCV57000

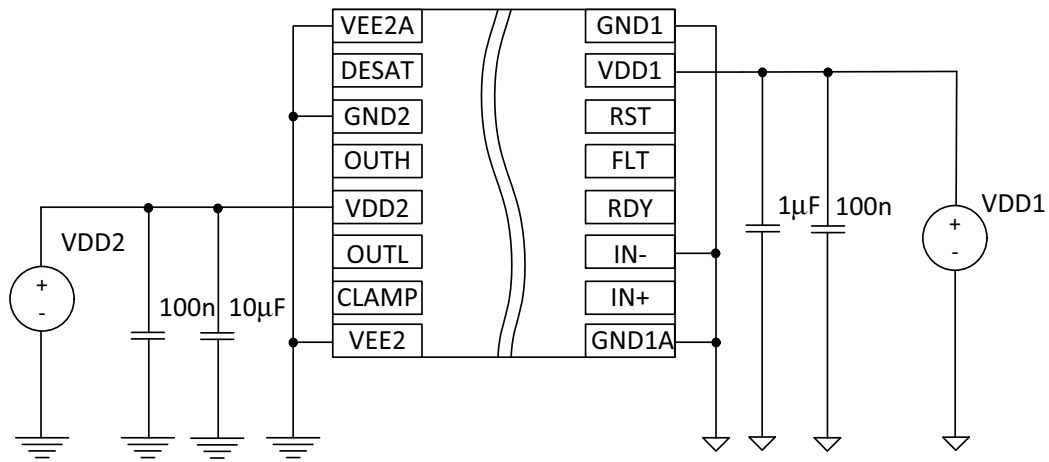


Figure 25. Unipolar Power Supply

## Common Mode Transient Immunity (CMTI)

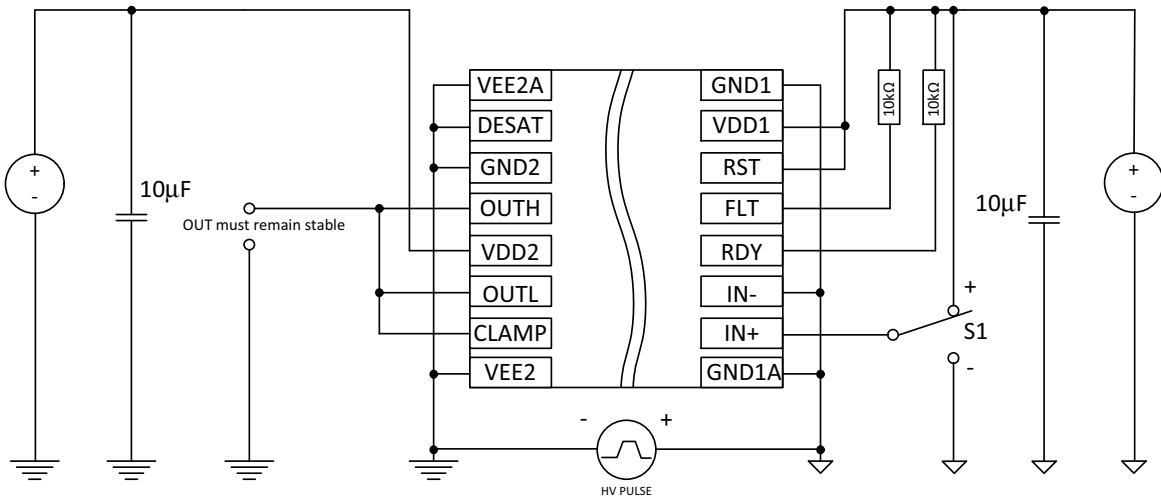


Figure 26. Common-Mode Transient Immunity Test Circuit

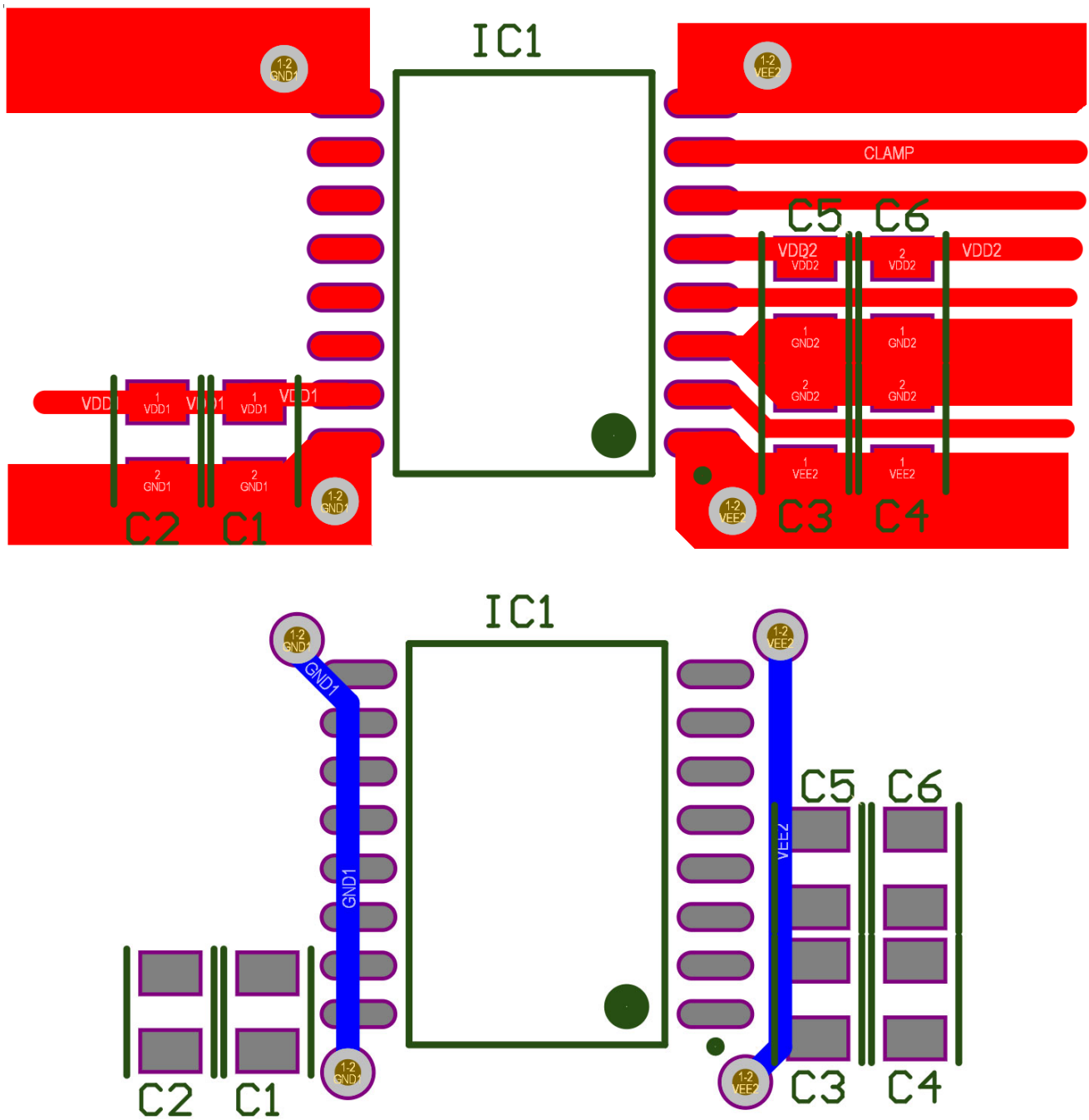


Figure 27. Recommended Basic Bipolar Power Supply PCB Design

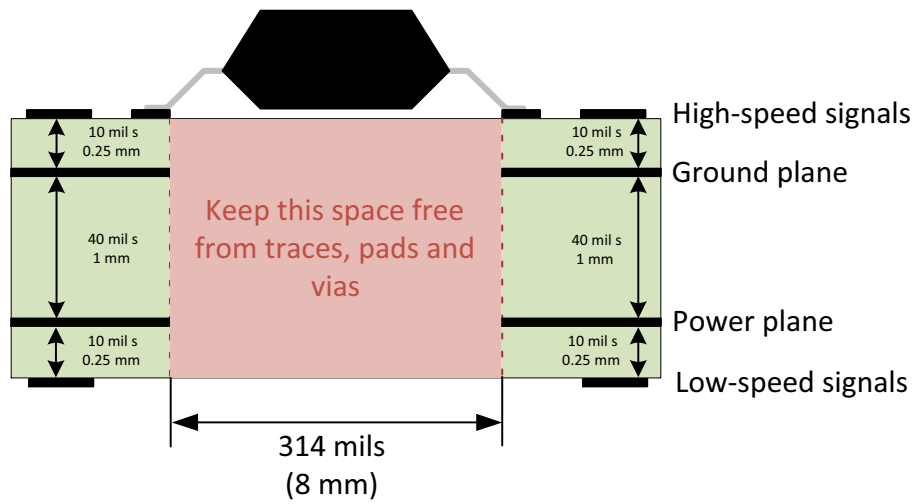
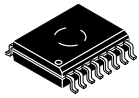
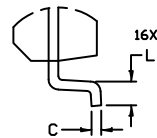
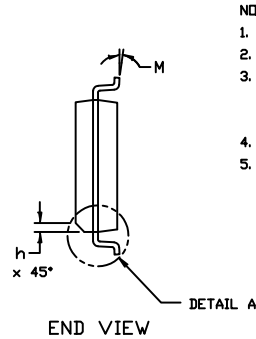
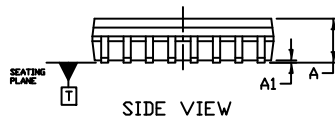
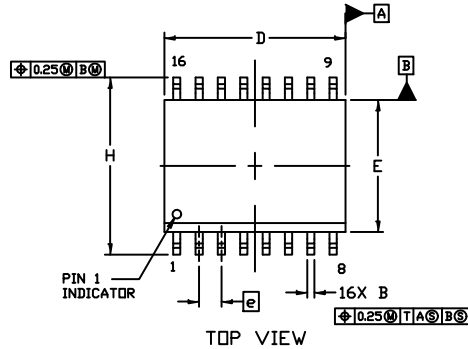


Figure 28. Recommended Layer Stack



1  
SCALE 1:1



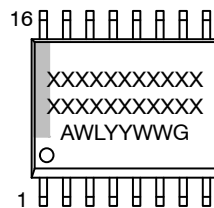
DETAIL A  
2X SCALE

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION.  
ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION OR FLASH TO BE 0.15 PER SIDE.

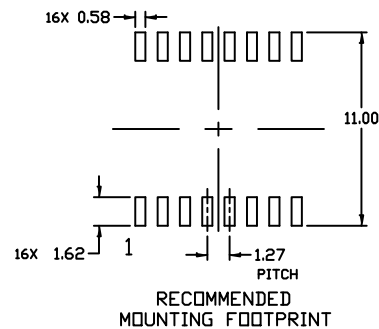
| DIM | MILLIMETERS |       |
|-----|-------------|-------|
|     | MIN.        | MAX.  |
| A   | 2.35        | 2.65  |
| A1  | 0.10        | 0.25  |
| B   | 0.35        | 0.49  |
| C   | 0.23        | 0.32  |
| D   | 10.15       | 10.45 |
| E   | 7.40        | 7.60  |
| e   | 1.27        | BSC   |
| H   | 10.05       | 10.55 |
| h   | 0.53        | REF   |
| L   | 0.50        | 0.90  |
| M   | 0°          | 7°    |

GENERIC  
MARKING DIAGRAM\*



XXXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
YY = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



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